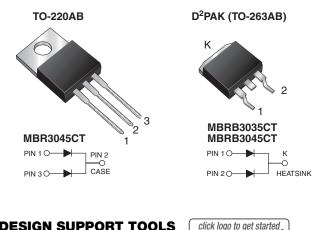
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MBR3045CT, MBRB3035CT, MBRB3045CT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



DESIGN SUPPORT TOOLS



| PRIMARY CHARACTERISTICS | | | | | |
|-----------------------------|---|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} 35 V, 45 V | | | | | |
| I _{FSM} | 200 A | | | | |
| V _F | 0.60 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | TO-220AB, D ² PAK (TO-263AB) | | | | |
| Circuit configurations | Common cathode | | | | |

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted) | | | | | | |
|---|--------------|--------------------|----------------------|------------|------|--|
| PARAMETER | | SYMBOL | MBRB3035CT | MBRB3045CT | UNIT | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | _{RRM} 35 45 | | | |
| Working peak reverse voltage | | V _{RWM} | 35 | 45 | V | |
| Maximum DC blocking voltage | | V _{DC} | 35 | 45 | | |
| Maximum average forward rectified current | total device | I _{F(AV)} | 30 | | | |
| | per diode | | 15 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 200 | | A | |
| Peak repetitive reverse current per diode at t_p = 2.0 µs, 1 kHz | | I _{RRM} | 2.0 | | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs | |
| Operating junction temperature range | | TJ | -65 to +150 | | °C | |
| Storage temperature range | | T _{STG} | -65 to +175 | | | |

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| ELECTRICAL CHARACTERISTICS ($T_c = 25 \ ^{\circ}C$ unless otherwise noted) | | | | | | | |
|--|-------------------------------|-----------------------|-------------------------|-------|------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUE | UNIT | | |
| | | I _F = 20 A | T _C = 125°C | 0.60 | | | |
| Maximum instantaneous forward voltage per diode | V _F ⁽¹⁾ | I _F = 30 A | $T_{C} = 25^{\circ}C$ | 0.76 | V | | |
| | | I _F = 30 A | T _C = 125°C | 0.72 | | | |
| Maximum instantaneous reverse current at DC blocking voltage per diode | I _R ⁽¹⁾ | Rated V _R | T _J = 25 °C | 1.0 | - mA | | |
| | | | T _J = 125 °C | 60 | | | |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 40 ms

| THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted) | | | | |
|--|---------------------|-----|------|------|
| PARAMETER | SYMBOL | MBR | MBRB | UNIT |
| Typical thermal resistance per diode | $R_{	ext{	heta}JC}$ | 1.5 | 1.5 | °C/W |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|--------------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | MBR3045CT-E3/4W | 1.85 | 4W | 50/tube | Tube | |
| TO-263AB | MBRB3045CT-E3/45 | 1.35 | 45 | 50/tube | Tube | |
| TO-263AB | MBRB3045CT-E3/81 | 1.35 | 81 | 800/reel | Tape and reel | |
| TO-263AB | MBRB3045CTHE3_A/P (1)(2) | 1.35 | Р | 50/tube | Tube | |
| TO-263AB | MBRB3045CTHE3_A/I (1)(2) | 1.35 | I | 800/reel | Tape and reel | |

Note

(1) AEC-Q101 qualified

⁽²⁾ 35 V device available in AEC-Q101 qualified D²PAK (TO-263AB) package only



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RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

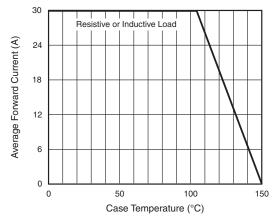


Fig. 1 - Forward Current Derating Curve

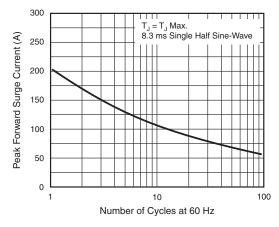


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

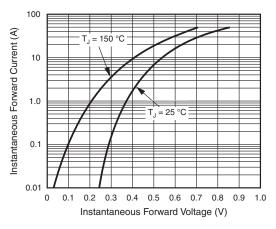


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

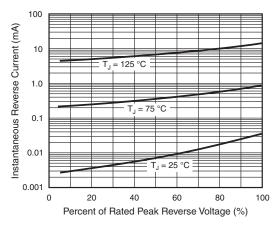


Fig. 4 - Typical Reverse Characteristics Per Diode

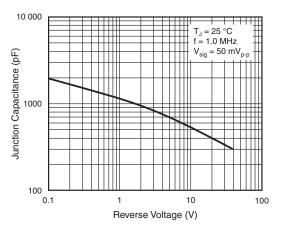


Fig. 5 - Typical Junction Capacitance Per Diode

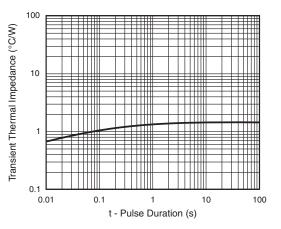


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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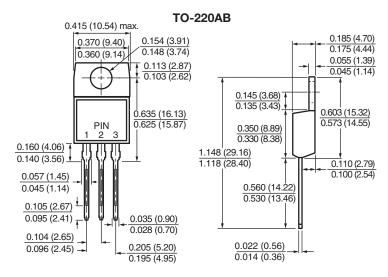
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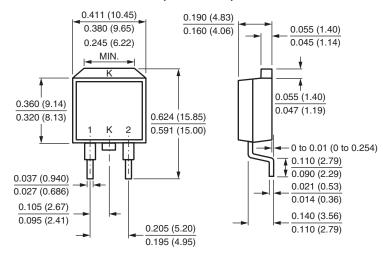


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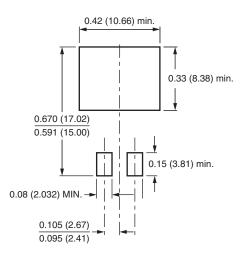
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)



Mounting Pad Layout



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